Diode Semiconductor Device - Page 1 of 1



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#### **Inclosure Material:**

Glass

**Overall Length:** 

0.200 inches

# **Terminal Length:**

1.000 inches

# **Overall Diameter:**

0.090 inches

End Application:

Blank system

### Mounting Method:

Terminal

### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

480.0 nonrepetitive peak reverse voltage, peak total value and 400.0 working peak reverse voltage

## **Current Rating Per Characteristic:**

5.00 amperes forward current, average preset and 400.00 milliamperes forward current, average absolute

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

# Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

2 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/240 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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